

*“Ferroelectric switching in FEFET : physics of the atomic mechanism and switching dynamics in HfZrO<sub>x</sub>, HfO<sub>2</sub> with oxygen vacancies and Si dopants”.* Clima S, O’Sullivan BJ, Ronchi N, Bardon MG, Banerjee K, Van den Bosch G, Pourtois G, van Houdt J, (2020). <http://doi.org/10.1109/IEDM13553.2020.9372117>